## Overview on Low-flux Detectors

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**DESY Hamburg** 

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### Introduction

- Very low noise detectors necessary to find/constrain low flux
- $\mathcal{O}(\text{few eV}) \Rightarrow \text{optics/ext. background easy}$  but int. background difficult
- Overlap with QI requirements
- To reduce int. background go to cryogenic temperatures

(Eisamann, et. al: Rev. Sci. Instrum. 82, 071101 (2011))

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 $\Rightarrow$  Expect some options

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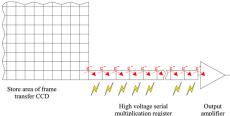
- Exemplary: PIXIS CCD used in ALPS-I
- Works out of the box
- Cooled to  $-70 \,^{\circ}\text{C}$  $\Rightarrow$  dark count rate  $R_{\text{DN}} = 7.5 \cdot 10^{-4} \, \frac{\text{ADU}}{\text{px s}}$
- Slow read-out  $\Rightarrow$  low RO-noise:  $\sigma_{RO} = 4.2$  ADU
- Low gain: 1.02  $\frac{e^-}{ADU}$
- Pixel size: 13 µm
- Sensitivity:  $\approx 6 \cdot 10^{-4} \frac{\text{photons}}{\text{s px}} (95 \% \text{ CL})$ (with 100 h dark and 20 h bright data, 80 % QE (@532 nm))



# Faint Flux EMCCD

- EMCCD: Multiply collected charges before RO-register
- Allows to ignore read-out noise
- Gain of EM *O*(1000)
- Interpret pixel value as binary: photon detected yes/no? (problematic for "high" fluxes: coincidences, CIC)
- "Count" photon if output signal  $> k\sigma$
- Sensitivity:  $\approx 2.8 \cdot 10^{-4} \frac{\text{photons}}{\text{s px}}$  (95 % CL) (with 20 h bright data, 80 % QE (@532 nm),  $R_{\text{DN}} = 7.5 \cdot 10^{-4} \frac{\text{ADU}}{\text{s px}}$ )

One cannot beat dark noise! → Cryogenic temperatures

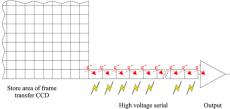


(Daigle, et. al.: [0908.0528])

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One cannot beat dark noise!  $\rightarrow$  Cryogenic temperatures



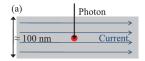
multiplication register

amplifier

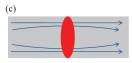
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## Superconducting Nanowire single-photon detector (SNSPD)

- SC nano wire with bias current just below j<sub>crit</sub>
- Absorbed photon creates normal conducting region
- Flux is expelled  $\Rightarrow$  flux density  $> j_{\rm crit}$
- $\bullet~$  Operating temperature  $\lesssim 4\,\text{K}$
- Meandering layout to create sensitive area  $\mathcal{O}(10 \times 10 \ \mu m^2)$
- Optical cavity to increase absorption efficiency
- Achieved efficiency  $\sim$  60 % @NIR
- But dark count rate  $> 0.1 \frac{\text{cnt}}{\text{s}}$  (Shen, Yang, Lou 2010)







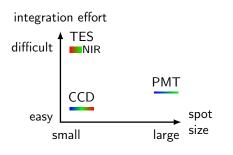


- Bolometric detector: photon absorption → temp. rise → signal
- Cryogenic read out: SQUID
- Couple signal into fiber
- $\bullet$  High QE (almost 100 %) for target wavelength
- Very low noise  $\sim 10^{-3} \, \frac{cnt}{s}$  (hopefully  $<\sim 10^{-5} \, \frac{cnt}{s}$ )
- Sensitivity:  $\approx 6.0\cdot 10^{-5}~\frac{\text{photons}}{\text{s px}}$  (95 % CL)

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#### For more details cf. talks by G. Cantatore & J. Dreyling-Eschweiler

- Large sensitive area
- Limited spectral range: 300-650 nm
- Limited QE:  $\lesssim$  30 %
- Low dark count rate, e.g.  $\sim 0.5 \; \frac{\rm cnt}{\rm s}$  for  $2.5 \, {\rm cm}^2$  sens. area  $\Rightarrow$  very good  $R_{\rm DN}/A_{\rm sens}$
- Sensitivity:  $\approx 1.7 \cdot 10^{-2} \frac{\text{photons}}{\text{s px}}$  (95 % CL)
- Superior to CCDs when signal cannot be focused on a few pixels



- Less options than I expected!
- Many devices still noisy (SNSPD, ...)
- Small spots:
  - CCD: easy but noisy
  - If you have the resources: Go for a TES!
- Large spots: PMT